Product data sheet Characteristics

TM3DQ32TK

module TM3 - 32 outputs transistor PNP HE10





Main

Range of product	Modicon TM3
Product or component type	Discrete output module
Range compatibility	Modicon M221 Modicon M241 Modicon M251
Discrete output type	Transistor
Discrete output number	32
Discrete output logic	Positive logic (source)
Discrete output voltage	24 V DC for transistor output
Discrete output current	100 mA for transistor output

Complementary

Discrete I/O number	32	
Current consumption	40 mA at 24 V DC via bus connector at state on 25 mA at 5 V DC via bus connector at state on 0 mA at 24 V DC via bus connector at state off 5 mA at 5 V DC via bus connector at state off	
Response time	450 μs for turn-off 450 μs for turn-on	
Leakage current	0.1 mA for transistor output	
Voltage drop	0.4 V	
Tungsten load	1.2 W for transistor output	
Local signalling	Green for output status	
Electrical connection	HE-10 connector for outputs	
Cable length	<= 5 m unshielded cable for transistor output	
Insulation	Non-insulated between outputs 500 V AC between output and internal logic	
Marking	CE	
Mounting support	Plate or panel with fixing kit Top hat type TH35-7.5 rail conforming to IEC 60715 Top hat type TH35-15 rail conforming to IEC 60715	
Height	90 mm	
Depth	81.3 mm	
Width	33.5 mm	
Product weight	0.112 kg	

Environment

Standards	EN/IEC 61131-2 EN/IEC 61010-2-201
Product certifications	C-Tick CULus
Resistance to electrostatic discharge	4 kV (on contact) conforming to EN/IEC 61000-4-2 8 kV (in air) conforming to EN/IEC 61000-4-2
Resistance to electromagnetic fields	1 V/m at 2 GHz3 GHz conforming to EN/IEC 61000-4-3 3 V/m at 1.4 GHz2 GHz conforming to EN/IEC 61000-4-3 10 V/m at 80 MHz1 GHz conforming to EN/IEC 61000-4-3
Resistance to magnetic fields	30 A/m at 5060 Hz conforming to EN/IEC 61000-4-8
Resistance to fast transients	1 kV for I/O conforming to EN/IEC 61000-4-4
Surge withstand	1 kV for I/O (DC) in common mode conforming to EN/IEC 61000-4-5

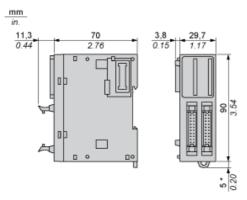
Radiated emissions, test level: 47 dBµV/m QP with class A, condition of test: 10 m (radio frequency: 230 MHz1 GHz) conforming to EN/IEC 55011
Radiated emissions, test level: 40 dBμV/m QP with class A, condition of test: 10 m (radio frequency: 30230 MHz) conforming to EN/IEC 55011
-1055 °C for horizontal installation -1035 °C for vertical installation
-2570 °C
1095 % without condensation in storage 1095 % without condensation in operation
IP20 with protective cover in place
2
02000 m
03000 m
3 gn (vibration frequency: 8.4150 Hz) on panel 3.5 mm (vibration frequency: 58.4 Hz) on panel 3 gn (vibration frequency: 8.4150 Hz) on DIN rail 3.5 mm (vibration frequency: 58.4 Hz) on DIN rail
15 gn (test wave duration:11 ms)

Offer Sustainability

Sustainable offer status	Green Premium product
RoHS (date code: YYWW)	Compliant - since 1348 - Schneider Electric declaration of conformity
REACh	Reference not containing SVHC above the threshold
Product environmental profile	Available Download Product Environmental
Product end of life instructions	Available Download End Of Life Manual



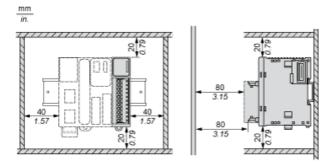
Dimensions



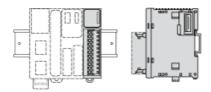
(*) 8.5 mm/0.33 in. when the clamp is pulled out.

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Spacing Requirements



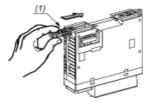
Mounting on a Rail



Incorrect Mounting

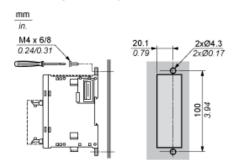


Mounting on a Panel Surface



(1) Install a mounting strip

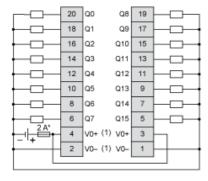
Mounting Hole Layout

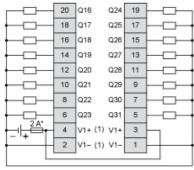


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Digital Transistor Output Module (32-channel, Source)

Wiring Diagram





- (*) Type T fuse
- (1) The V0+ terminals are connected internally.
 - The V0- terminals are connected internally.
 - The V1+ terminals are connected internally.
 - The V1- terminals are connected internally.
 - The V0+ and V1+ terminals are not connected internally.
 - The V0- and V1- terminals are not connected internally.